

Institute of High Energy Physics, Chinese Academy of Sciences

High-granularity crystal calorimeter: the first module development and beam test

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Crystal module development and beam test:

- Recap: crystal module development
 - Uniformity scan of BGO crystal bars
 - Mechanical and PCB design
 - Electronics and trigger scheme
- Crystal module beam tests at CERN T9 beam line

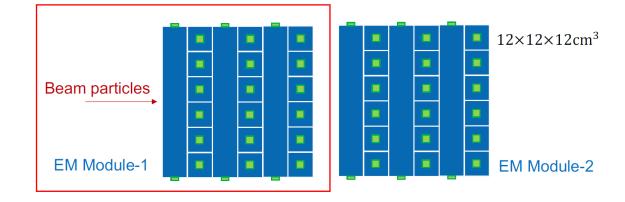


Introduction to the first small-scale crystal module

- Motivations: address critical issues at system level
- First $12 \times 12 \times 12$ cm³ BGO modules development
 - Crystal: 36 BGO crystal ($12 \times 2 \times 2$ cm³) from SIC-CAS
 - SiPM: HPK 10 μ m pixel size, 3 \times 3 mm² sensitive area
 - Electronics: Citiroc-1A chips
- Beam test plan
 - Muon, electron and pion data at CERN T9 beam line for the first module (generally < 10 GeV/c)
 - Future plan: 2 modules serial arrangement







Beam test for the first module: 72 channels, double-sided readout

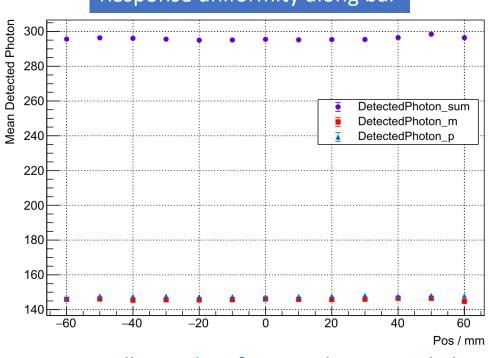


- 36 crystals wrapped with ESR and Al foil
 20 printed
- 3D printed support structure



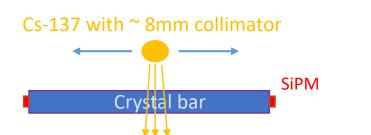
Uniformity scan of BGO crystal bars

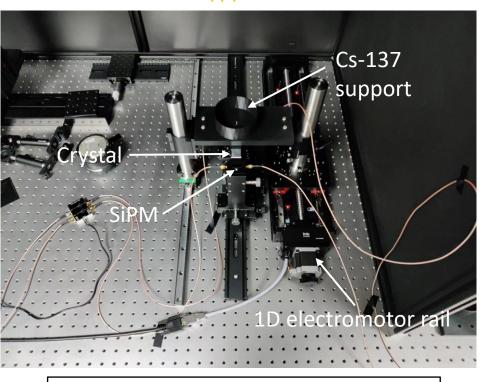
- Batch test of SIC-CAS BGO crystal bars
 - 40 crystals with ESR and Al foil wrapping
 - Scan with Cs-137 radioactive source



Response uniformity along bar

• Generally good uniformity along a single bar



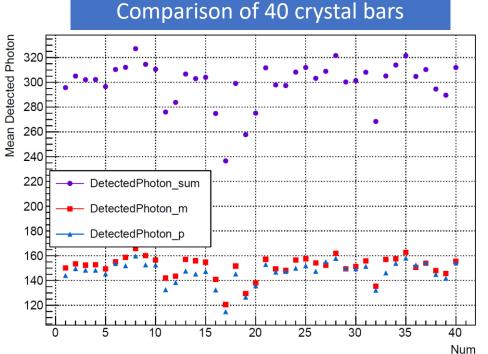


Automatic crystal scan with electromotor stage

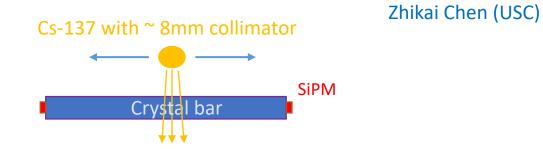


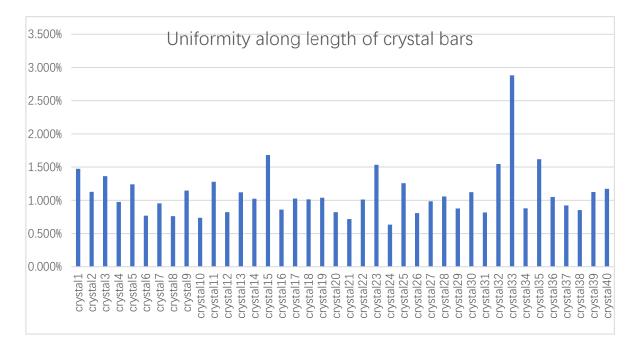
Uniformity scan of BGO crystal bars

- Batch test of SIC-CAS BGO crystal bars
 - 40 crystals with ESR and Al foil wrapping
 - Scan with Cs-137 radioactive source



- Tested point: crystal center
- Response varies among bars: coupling? wrapping?



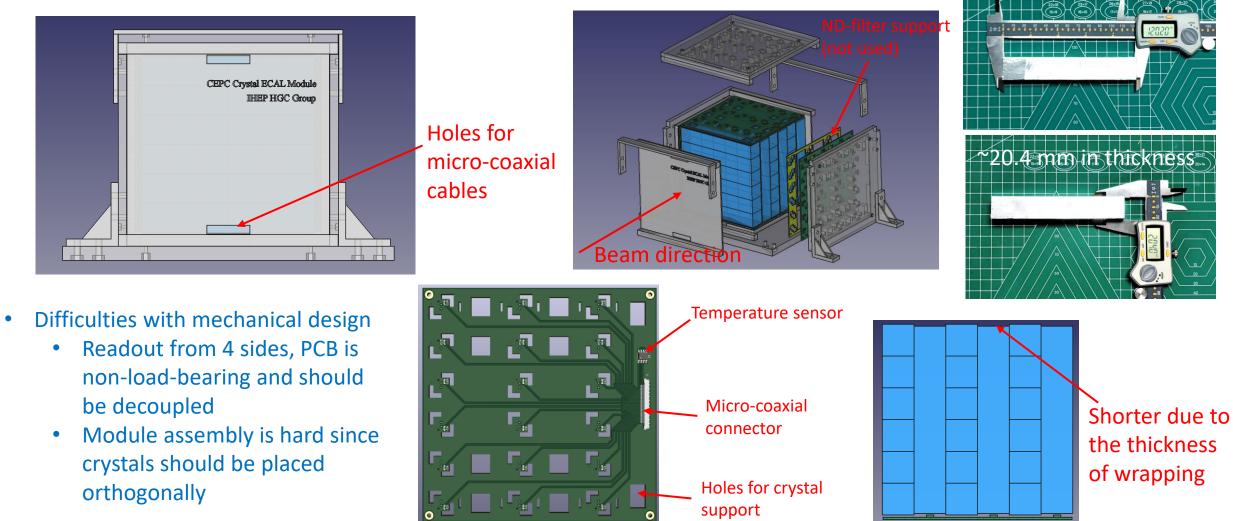


- Uniformity = (Max Min)/Mean
- Generally uniformity of single bars at 1% level



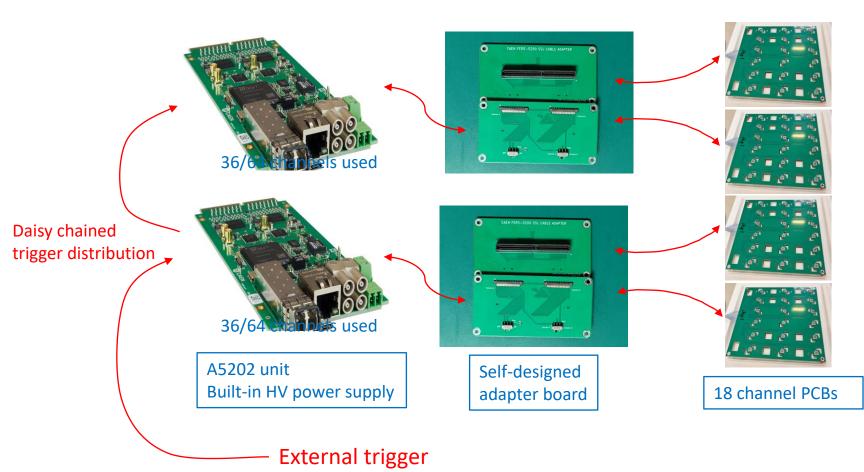
Mechanical and PCB design

• Mechanical structure and module assembly method



Electronics and trigger scheme

• Electronics: two A5202 units with self-trigger or external trigger



- Acquisition mode: High gain & Low gain & Timing
- Event synchronization: triggers within 20 ns of the two units
- External trigger: daisy chain
- Self-trigger: coincidence of 2 PCBs of one unit



Crystal module development and beam test:

- Recap: crystal module development
- Crystal module beam tests at CERN T9 beam line
 - Transport and preparations
 - Installation of module
 - Beam test with muon, electron and pion
 - Summary and data analysis plan



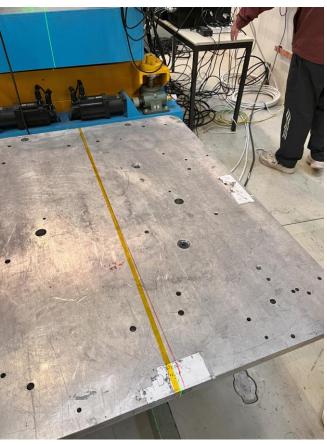
Transport and preparations

• Transportation: started on May 6th and finished in May 16th



Flight case in total ~75 kg

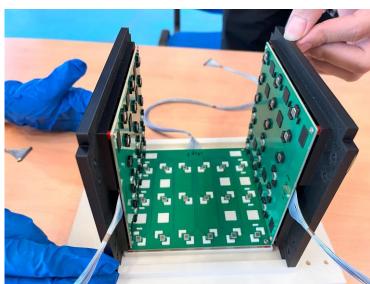




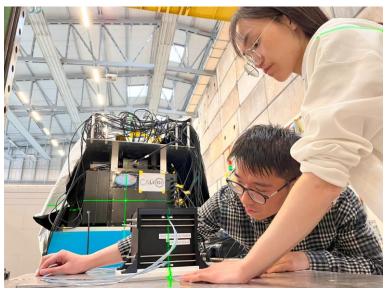
Lifting table for crystal module in front of ScW ECAL and AHCAL

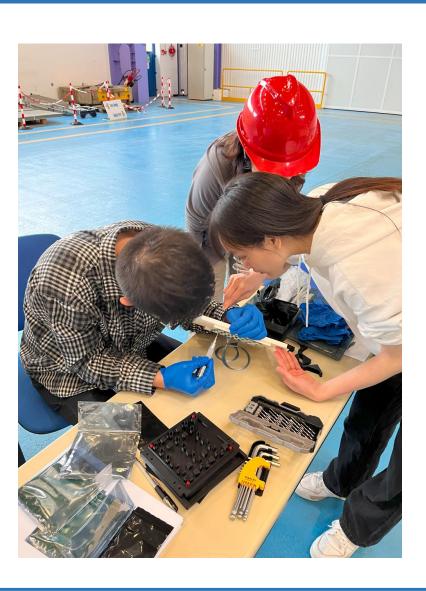
Installation of module









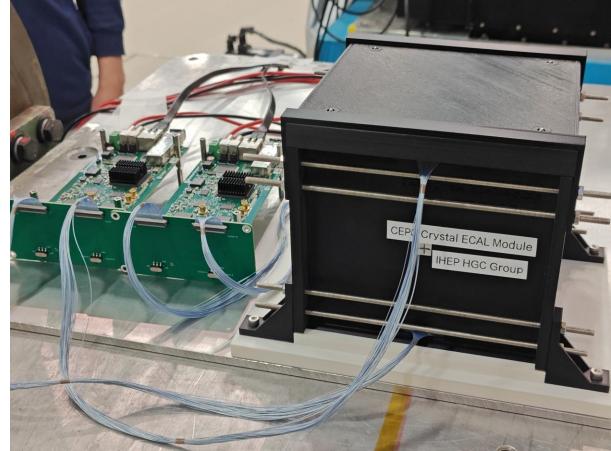




Installation of module

Connection scheme for the chained run starting and external trigger





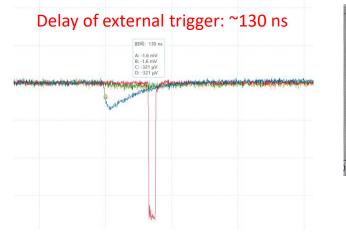
Thanks to the efforts of Yong, Dejing, Baohua, Zhiyu and Lijun!

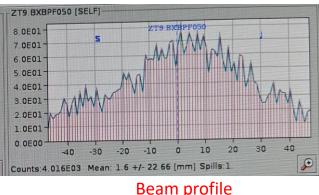


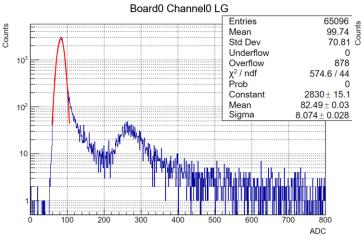
Beam test with muon: parameter scans

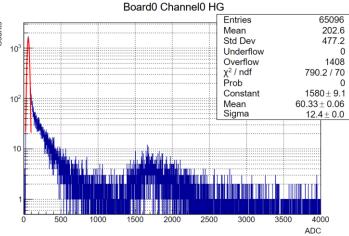
- External trigger from beam telescopes in front of beam pipe: ~2k per spill
- 10 GeV/c muon- beam: MIP response
 - High-gain and Low-gain scans
 - Hold-Delay time scans
 - Shaping time scans
 - Position, HG discriminator scans

HG	LG	Hold-Delay Time	Shaping Time	
34	4	5 ns	12.5 ns	
44	24	10 ns	25 ns	
49	34	50 ns	37.5 ns	
54	44	100 ns	50 ns	
59	52	150 ns	62.5 ns	
	56	200 ns	75 ns	
	58	300 ns	87.5 ns	
	61			
	62			
	63			







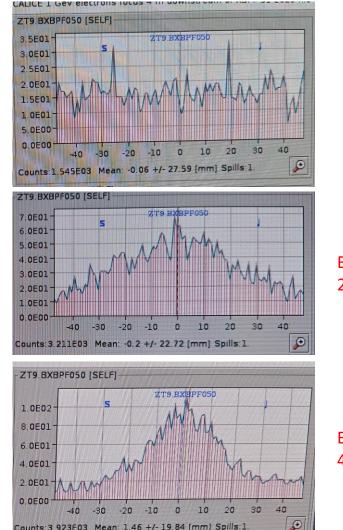


Beam test with electron: energy scans

- Energy scans: 0.5~5 GeV/c e- beam
 - Hold-Delay set to 200 ns
 - Shaping time set to 87.5 ns (maximum)
 - HG 49, LG 34/44/56, larger value for low energy particles •

Momentum	HG	LG	#Run (10k per run)		
0.5	49	56	2	\mathcal{A}	Much lower
1	49	44/56	16	\int	trigger rate
2	49	34/44	20	_	
3	49	34/44	20		
4	49	34/44	20		
5	49	34	10		

Some data with different HG parameter will be included later



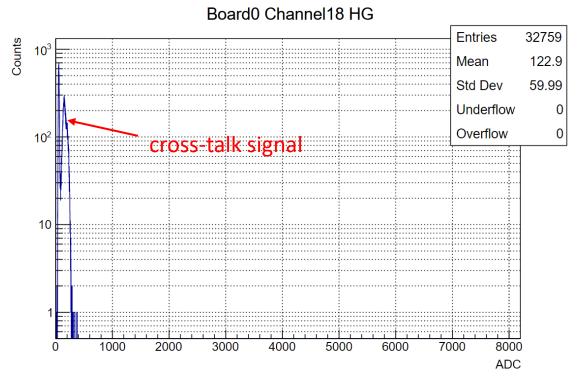
Counts: 3.923E03 Mean: 1.46 +/- 19.84 [mm] Spills: 1

Beam profile 1 GeV/c

Beam profile 2 GeV/c

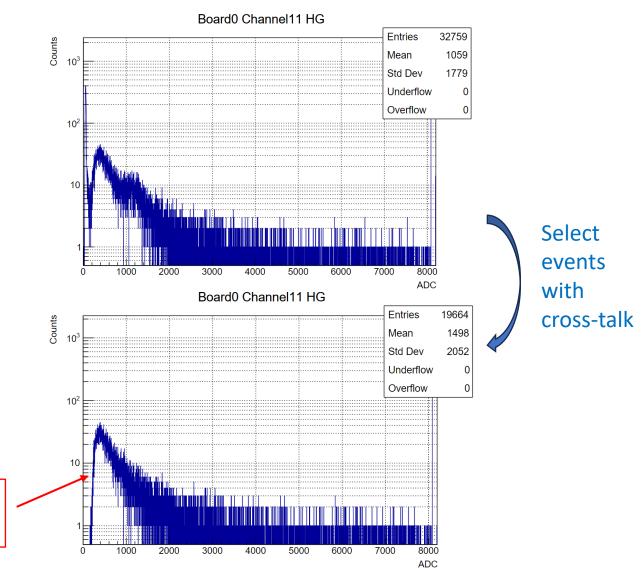


Beam test with electron: issues



• Channels without SiPM connection: cross-talk signal

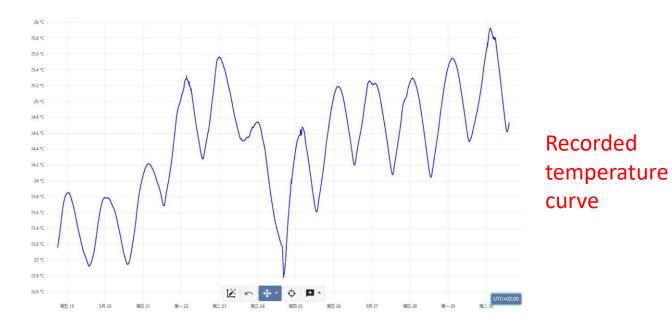
Seems MIP signal and pedestal have been removed Still need to be investigated





Other data acquired

- Parasitic test: self-trigger of "leaked particles" form upstream
 - Almost MIP-like particles
 - Hold-Delay scan result is different: delay of the external trigger is longer
 - Validation of long-term data-taking capability
- Pion- beam test: capability under high fluence
 - > 80% trigger lost
- Temperature monitoring





Summary and data analysis plan

- The beam test for the first crystal module has been successfully completed!
- Data conversion and selection: synchronized event
- Geant4 simulation of one module: EM energy resolution
- Event display tool
- MIP calibration channel by channel
- Energy reconstruction of electron data
- Correction of cross-talk
- Analysis of timing information
- Influence of background radiation from lifting table

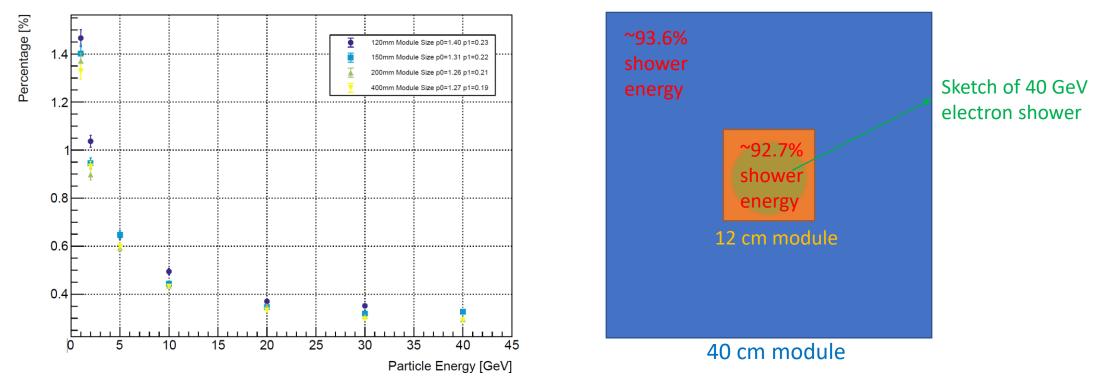


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Crystal-SiPM module design: impact of module size

• $40 \times 40 \times 28$ supercell: change the length of the crystal bar from 400 mm to 120 mm

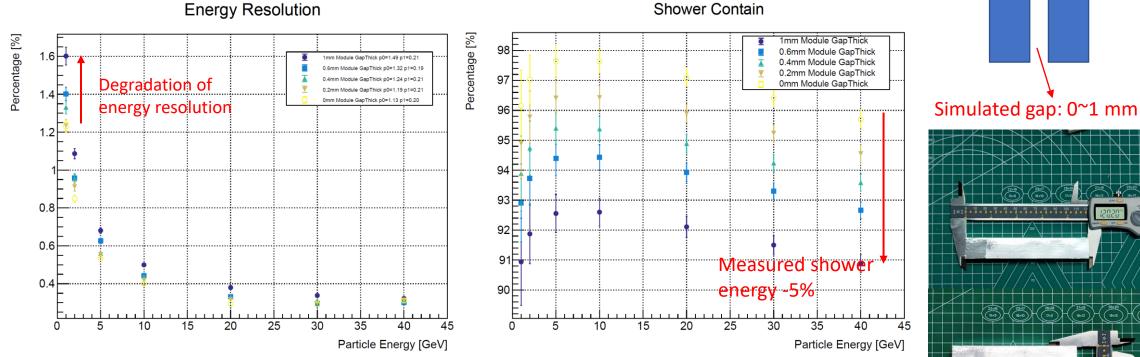


Energy Resolution

- For EM showers, 12 cm size is enough to contain most of the energy when particles hit on the center of the module
- Degradation of energy resolution: ~0.1% level

Crystal-SiPM module design: impact of gaps

- Gap material in $40 \times 40 \times 28$ supercell: ESR film, Al foil, Air •
- Density has been set to 2 g/cm^3

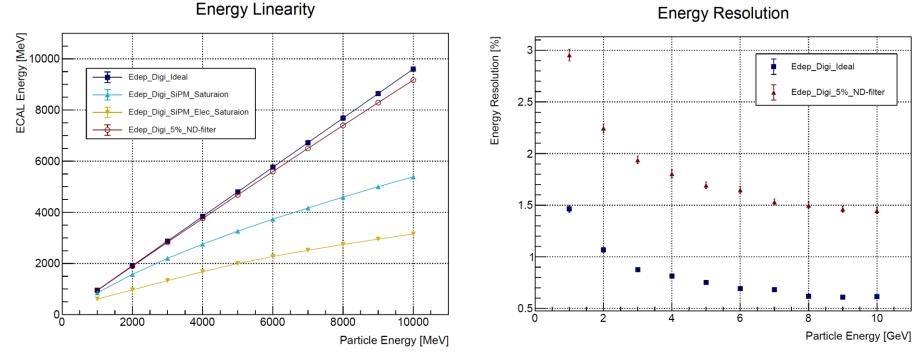


- Impact of gaps is more significant than module size
- Gaps for $12 \times 2 \times 2$ cm³ cm crystal: ~0.4 mm
- Control of gaps will be harder with longer crystals: key issue



Activities on small-scale crystal module design

- Performance check: Geant4 simulation with 1~10 GeV electron
- Saturation considering S14160-3010PS SiPM and Citiroc-1A chip
- 5% (σ = 0.1%) transmittance neutral density filter is used for light attenuation



- SiPM non-linearity should be further calibrated
- Saturation of electronics can be avoided via high dynamic range ASIC
- 5% neutral density filter can mitigate the saturation effect but will introduce additional uncertainty

Digitization: photon statistics, SiPM gain error, ADC error, MIP threshold

Geant4 Simulation (v11.0)